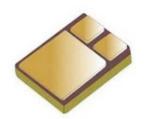


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Features

- JANS and JANSR Qualified to MIL-PRF-19500/544
- JEDEC Registered 2N5154
- Lightweight & Low Power
- Ideal for Space, Military, and Other High Reliability Applications
- Surface Mount U3 Package



Electrical Characteristics

| Parameter | Test Conditions | Symbol | Units | Min. | Max. | | |
|---|---|----------------------|--------------|----------------|--------------|--|--|
| Off Characteristics | | | | | l | | |
| Collector - Emitter Breakdown Voltage | I _C = 100 mAdc, I _B = 0 | | Vdc | 80 | _ | | |
| Emitter - Base Cutoff Current | $V_{EB} = 4.0 \text{ Vdc}, I_{C} = 0$ $V_{EB} = 5.5 \text{ Vdc}, I_{C} = 0$ | | µAdc mAdc | _ | 1.0 1.0 | | |
| Collector - Emitter Cutoff Current | $V_{CE} = 60 \text{ Vdc}, V_{BE} = 0$ $V_{CE} = 100 \text{ Vdc}, V_{BE} = 0$ | I _{CES} | µAdc mAdc | _ | 1.0 1.0 | | |
| Collector - Emitter Cutoff Current | V _{CE} = 40 Vdc, I _B = 0 | I _{CEO} | μAdc | _ | 50 | | |
| On Characteristics ¹ | | | | | | | |
| Forward Current Transfer Ratio | I_{C} = 50 mAdc, V_{CE} = 5.0 Vdc I_{C} = 2.5 Adc, V_{CE} = 5.0 Vdc I_{C} = 5.0 Adc, V_{CE} = 5.0 Vdc | H _{FE} | - | 50 70 40 | 200 — | | |
| Collector - Emitter Saturation Voltage | I_C = 2.5 Adc, I_B = 250 mAdc I_C = 5.0 Adc, I_B = 500 mAdc | V _{CE(SAT)} | Vdc | _ | 0.75 1.50 | | |
| Emitter - Base Voltage Non-Saturation | $I_C = 2.5 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc}$ | V _{BE(ON)} | Vdc | _ | 1.45 | | |
| Emitter - Base Saturation Voltage | $I_C = 2.5 \text{ Adc}, I_B = 250 \text{ mAdc}$ $I_C = 5.0 \text{ Adc}, I_B = 500 \text{ mAdc}$ | V _{BE(SAT)} | Vdc | _ | 1.45 2.20 | | |
| Dynamic Characteristics | | | | | | | |
| Magnitude of Common Emitter Small-Signal Short-Circuit Forward Current Transfer Ratio | I_{C} = 500 mAdc, V_{CE} = 5.0 Vdc, f = 10 mHz | H _{FE} | - | 7 | _ | | |
| Small-Signal Short-Circuit Forward Current Transfer Ratio | I_{C} = 100 mAdc, V_{CE} = 5.0 Vdc, f = 10 mHz | H _{FE} | - | 50 | _ | | |
| Output Capacitance | V _{CB} = 10 Vdc, I _E = 0, f = 1 MHz | Сово | pF | _ | 250 | | |
| Switching Characteristics | | | | | | | |
| Turn-On Time | I _C = 5.0 Adc; I _{B1} = 500 mAdc | T _{ON} | μs | _ | 0.5 | | |
| Turn-Off Time | R _L = 6 Ω | T _{OFF} | μs | _ | 1.5 | | |
| Storage Time | I _{B2} = -500 mAdc | Ts | μs | _ | 1.4 | | |
| Fall Time | V _{BE(OFF)} = 3.7 Vdc | T _f | μs | _ | 0.5 | | |

Safe Operating Area

 $\begin{array}{lll} \text{DC Tests:} & & & & & & & & & \\ \text{Test 1:} & & & & & & & \\ \text{Test 2:} & & & & & & \\ \text{Test 3:} & & & & & & \\ \end{array} \begin{array}{ll} \text{T}_{\text{C}} = +25^{\circ}\text{C}, \text{ I Cycle, t} = 1.0 \text{ s} \\ \text{V}_{\text{CE}} = 5.0 \text{ Vdc, I}_{\text{C}} = 2.0 \text{ Adc} \\ \text{V}_{\text{CE}} = 32 \text{ Vdc, I}_{\text{C}} = 310 \text{ mAdc} \\ \text{V}_{\text{CE}} = 32 \text{ Vdc, I}_{\text{C}} = 310 \text{ mAdc} \\ \text{V}_{\text{CE}} = 80 \text{ Vdc, I}_{\text{C}} = 12.5 \text{ mAdc} \\ \end{array}$

^{1.} Pulse Test: Pulse Width = 300 µs, Duty Cycle ≤2.0%.



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Absolute Maximum Ratings^{2,3}

| Ratings | Symbol | Value |
|--|------------------------------------|-----------------|
| Collector - Emitter Voltage | V _{CEO} | 80 Vdc |
| Collector - Base Voltage | V _{CBO} | 100 Vdc |
| Emitter - Base Voltage | V _{EBO} | 5.5 Vdc |
| Collector Current | I _C | 2 Adc |
| Total Power Dissipation @ $T_A = 25^{\circ}C$ @ $T_C = 25^{\circ}C$ | P _T | 1.0 W 100 W |
| Operating & Storage Temperature Range | T _{OP} , T _{STG} | -65°C to +200°C |

^{1.} Refer to 19500/544 for thermal derating curves.

Thermal Characteristics

| Characteristics | Symbol | Max. Value |
|--------------------------------------|----------------|------------|
| Thermal Resistance, Junction to Case | $R_{	heta JC}$ | 1.7°C/W |

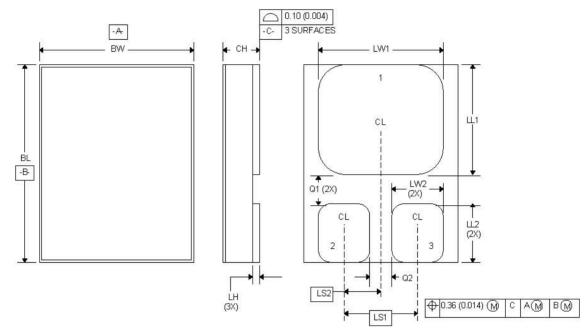
^{2.} This value applies for PW ≤ 8.3ms, duty cycle ≤ 1%.



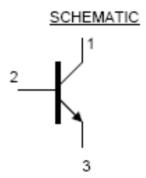
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Outline Drawing (U3)



- 1. Dimensions are in inches.
- Millimeters are given for general information only.
 In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.
- 4. Terminal 1 collector, terminal 2 -base, terminal 3 emitter.



| | Dimensions | | | | |
|-----------------|------------|--------|-------------|-------|--|
| Ltr | Inches | | Millimeters | | |
| | Min. | Max. | Min. | Max. | |
| BL | 0.395 | 0.405 | 10.03 | 10.29 | |
| BW | 0.291 | 0.301 | 7.40 | 7.65 | |
| CH | 0.1085 | 0.1205 | 2.76 | 3.06 | |
| LH | 0.010 | 0.020 | 0.25 | 0.51 | |
| LW ₁ | 0.281 | 0.291 | 7.14 | 7.39 | |
| LW ₂ | 0.090 | 0.100 | 2.29 | 2.54 | |
| LL ₁ | 0.220 | 0.230 | 5.59 | 5.84 | |
| LL ₂ | 0.115 | 0.125 | 2.92 | 3.18 | |
| LS ₁ | 0.150 BSC | | 3.81 BSC | | |
| LS ₂ | 0.075 BSC | | 1.91 BSC | | |
| Q ₁ | 0.030 | | 0.762 | | |
| Q ₂ | 0.030 | | 0.762 | | |

2N5154U3



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